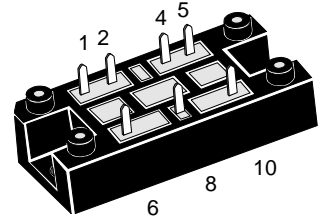
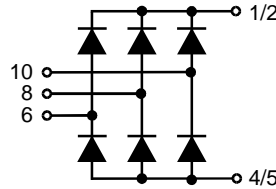


Three Phase Rectifier Bridge

$I_{dAVM} = 82 \text{ A}$
 $V_{RRM} = 800-1800 \text{ V}$

| V_{RSM} V | V_{RRM} V | Type |
|----------------|----------------|--------------|
| 900 | 800 | VUO 80-08NO1 |
| 1300 | 1200 | VUO 80-12NO1 |
| 1500 | 1400 | VUO 80-14NO1 |
| 1700 | 1600 | VUO 80-16NO1 |
| 1900 | 1800 | VUO 80-18NO1 |



| Symbol | Test Conditions | Maximum Ratings |
|------------------------------------|---|---|
| I_{dAV} I_{dAVM} | $T_K = 90^\circ\text{C}$, module module | 82 A 82 A |
| I_{FSM} | $T_{VJ} = 45^\circ\text{C}$; $V_R = 0$ | t = 10 ms (50 Hz), sine 600 A t = 8.3 ms (60 Hz), sine 640 A |
| | $T_{VJ} = T_{VJM}$ $V_R = 0$ | t = 10 ms (50 Hz), sine 520 A t = 8.3 ms (60 Hz), sine 555 A |
| I^2t | $T_{VJ} = 45^\circ\text{C}$ $V_R = 0$ | t = 10 ms (50 Hz), sine 1800 A ² s t = 8.3 ms (60 Hz), sine 1720 A ² s |
| | $T_{VJ} = T_{VJM}$ $V_R = 0$ | t = 10 ms (50 Hz), sine 1350 A ² s t = 8.3 ms (60 Hz), sine 1295 A ² s |
| T_{VJ} T_{VJM} T_{stg} | | -40...+150 °C 150 °C -40...+130 °C |
| V_{ISOL} | 50/60 Hz, RMS $I_{ISOL} \leq 1 \text{ mA}$ | t = 1 min 3000 V~ t = 1 s 3600 V~ |
| | M_d | Mounting torque (M5) (10-32UNF) |
| Weight | typ. | 35 g |

Features

- Package with DCB ceramic base plate
- Isolation voltage 3600 V~
- Planar passivated chips
- Blocking voltage up to 1800 V
- Low forward voltage drop
- Leads suitable for PC board soldering
- UL registered E72873

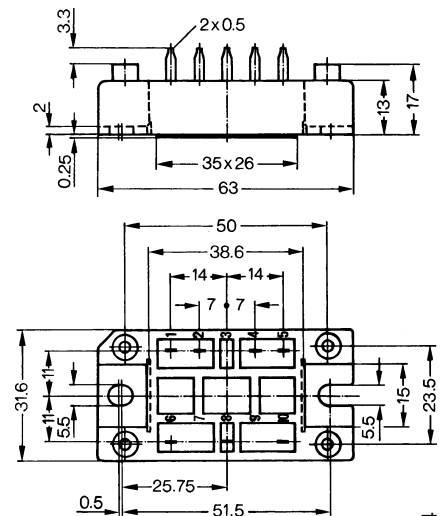
Applications

- Supplies for DC power equipment
- Input rectifiers for PWM inverter
- Battery DC power supplies
- Field supply for DC motors

Advantages

- Easy to mount with two screws
- Space and weight savings
- Improved temperature and power cycling

Dimensions in mm (1 mm = 0.0394")



| Symbol | Test Conditions | Characteristic Values |
|------------|---|-----------------------|
| I_R | $V_R = V_{RRM}$ $T_{VJ} = 25^\circ\text{C}$ | $\leq 0.3 \text{ mA}$ |
| | $V_R = V_{RRM}$ $T_{VJ} = T_{VJM}$ | $\leq 6 \text{ mA}$ |
| V_F | $I_F = 80 \text{ A}$; $T_{VJ} = 25^\circ\text{C}$ | $\leq 1.5 \text{ V}$ |
| V_{T0} | For power-loss calculations only | 0.8 V |
| r_T | | 7.5 mΩ |
| R_{thJH} | per diode, 120° rect. | 1.42 K/W |
| | per module, 120° rect. | 0.24 K/W |
| d_s | Creeping distance on surface | 12.7 mm |
| d_A | Creepage distance in air | 9.4 mm |
| a | Max. allowable acceleration | 50 m/s ² |

Data according to IEC 60747 and refer to a single diode unless otherwise stated.
 IXYS reserves the right to change limits, test conditions and dimensions.

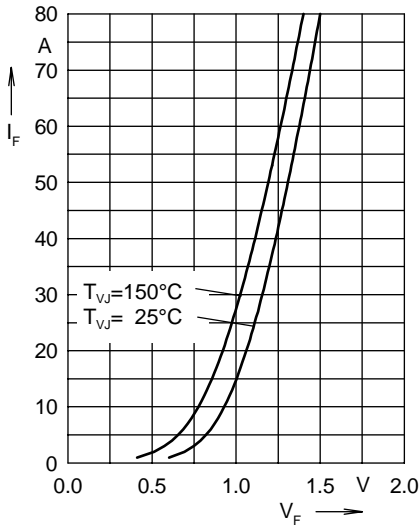


Fig. 1 Forward current versus voltage drop per diode

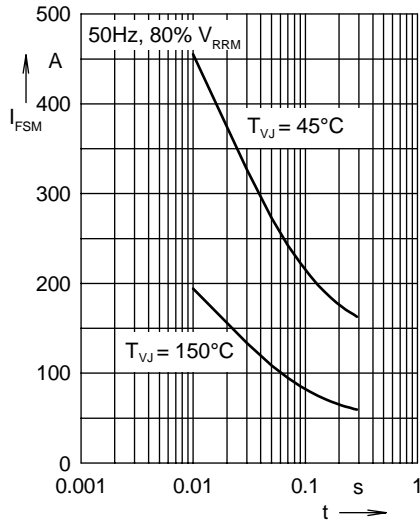


Fig. 2 Surge overload current

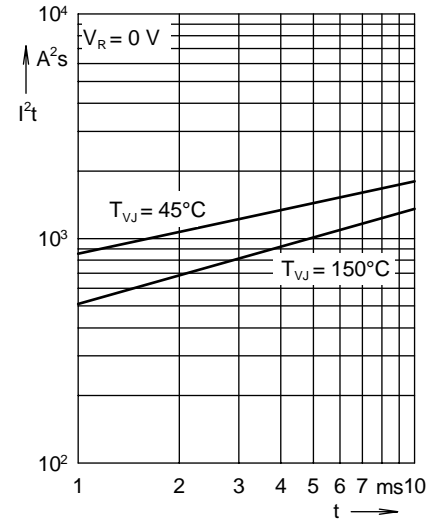


Fig. 3 I^2t versus time per diode

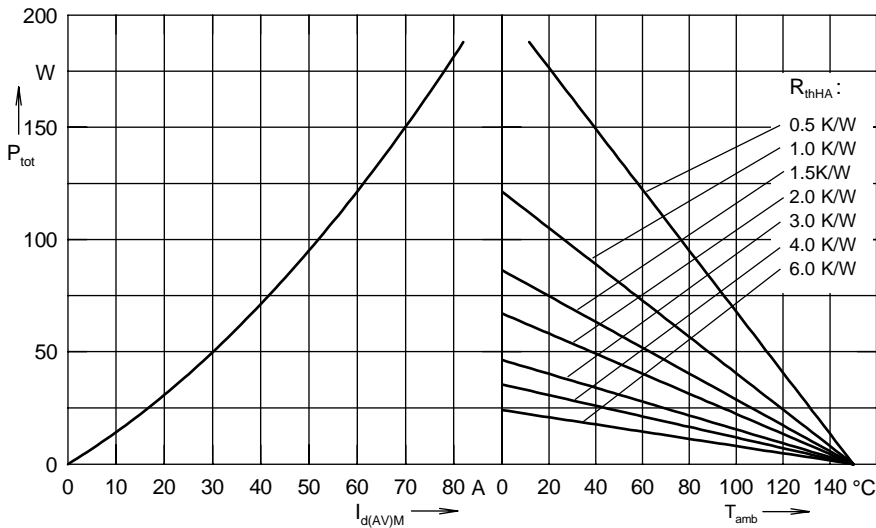


Fig. 4 Power dissipation versus direct output current and ambient temperature

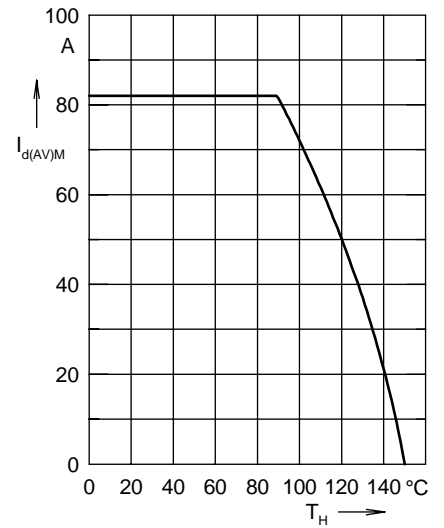


Fig. 5 Max. forward current versus heatsink temperature

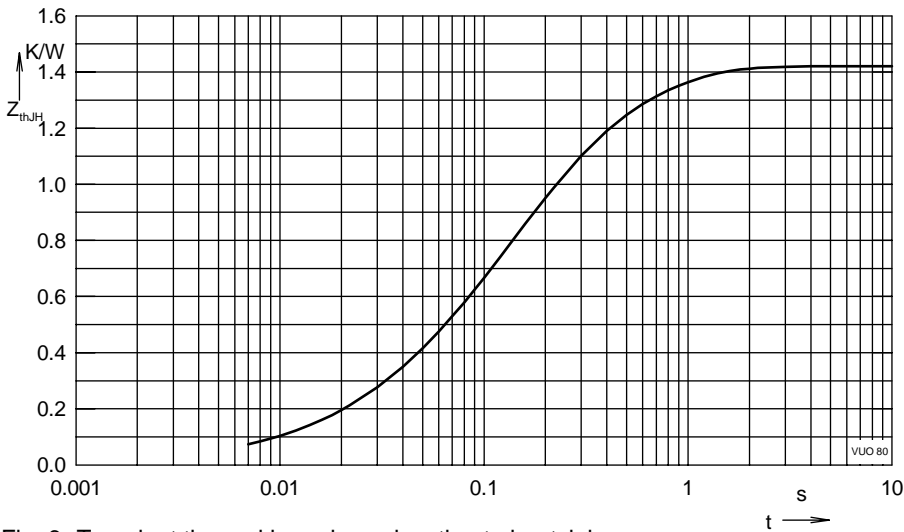


Fig. 6 Transient thermal impedance junction to heatsink

Constants for Z_{thJH} calculation:

| i | R_{thi} (K/W) | t_i (s) |
|---|-----------------|-----------|
| 1 | 0.005 | 0.01 |
| 2 | 0.21 | 0.05 |
| 3 | 0.795 | 0.14 |
| 4 | 0.41 | 0.5 |

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